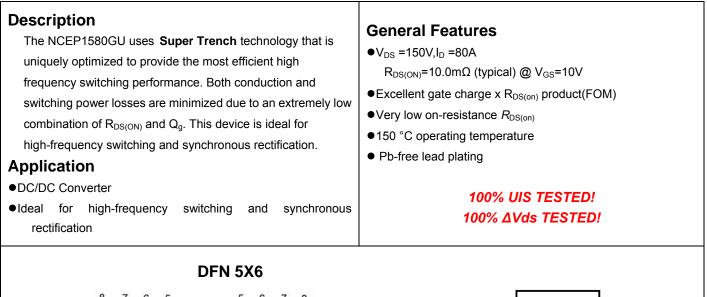
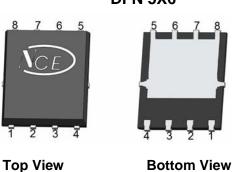
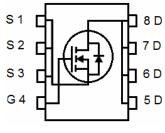


## NCE N-Channel Super Trench Power MOSFET







**Schematic Diagram** 

### Package Marking and Ordering Information

3

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCEP1580GU	NCEP1580GU	DFN5X6-8L	-	-	-

### Absolute Maximum Ratings (T<sub>A</sub>=25<sup>°</sup>C unless otherwise noted)

Parameter	Symbol	/mbol Limit	
Drain-Source Voltage	V <sub>DS</sub>	150	V
Gate-Source Voltage	V <sub>GS</sub>	±20	V
Drain Current-Continuous	Ι <sub>D</sub>	80	А
Drain Current-Continuous(T <sub>C</sub> =100℃)	I <sub>D</sub> (100℃)	52	A
Pulsed Drain Current	I <sub>DM</sub>	320	A
Maximum Power Dissipation	PD	160	W
Derating factor		1.28	W/°C
Single pulse avalanche energy (Note 5)	E <sub>AS</sub>	550	mJ
Operating Junction and Storage Temperature Range	T <sub>J</sub> ,T <sub>STG</sub>	-55 To 150	°C

#### **Thermal Characteristic**

Thermal Résistance, Junction-to-Case <sup>(Note 2)</sup>	R <sub>θJC</sub>	0.78	°C/W
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## Electrical Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

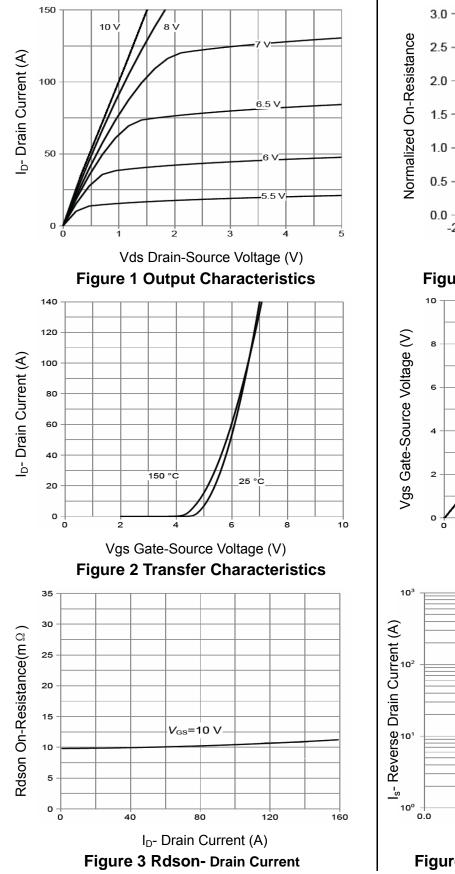
Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics	· · ·					
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250µA	150	-	-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS}$ =150V, $V_{GS}$ =0V	-	-	1	μA
Gate-Body Leakage Current	I <sub>GSS</sub>	$V_{GS}$ =±20V, $V_{DS}$ =0V	-	-	±100	nA
On Characteristics (Note 3)	· · ·					
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS}=V_{GS}$ , I <sub>D</sub> =250µA	2.0		4.0	V
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	$V_{GS}$ =10V, I <sub>D</sub> =40A	-	10	11.5	mΩ
Forward Transconductance	<b>g</b> fs	V <sub>DS</sub> =5V,I <sub>D</sub> =40A	-	58	-	S
Dynamic Characteristics (Note4)	· · ·					
Input Capacitance	C <sub>lss</sub>		-	2200	2700	PF
Output Capacitance	C <sub>oss</sub>	V <sub>DS</sub> =75V,V <sub>GS</sub> =0V, F=1.0MHz	-	289	450	PF
Reverse Transfer Capacitance	C <sub>rss</sub>		-	11.2	18	PF
Switching Characteristics (Note 4)	· · ·					
Turn-on Delay Time	t <sub>d(on)</sub>		-	12.5	-	nS
Turn-on Rise Time	tr	V <sub>DD</sub> =75V, I <sub>D</sub> =40A	-	3.8	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GS}$ =10V, $R_{G}$ =3 $\Omega$	-	14	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	3.5	-	nS
Total Gate Charge	Qg		-	33	40	nC
Gate-Source Charge	Q <sub>gs</sub>	V <sub>DS</sub> =75V,I <sub>D</sub> =40A, V <sub>GS</sub> =10V	-	14.5	18	nC
Gate-Drain Charge	Q <sub>gd</sub>	V <sub>GS</sub> =10V	-	8	10	nC
Drain-Source Diode Characteristics	·····			•		
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =40A	-	-	1.2	V
Diode Forward Current (Note 2)	I <sub>S</sub>		-	-	80	А
Reverse Recovery Time	t <sub>rr</sub>	$T_J$ = 25°C, $I_F$ = 40A	-	47	-	nS
Reverse Recovery Charge	Qrr	di/dt = 100A/µs <sup>(Note3)</sup>	-	55	-	nC

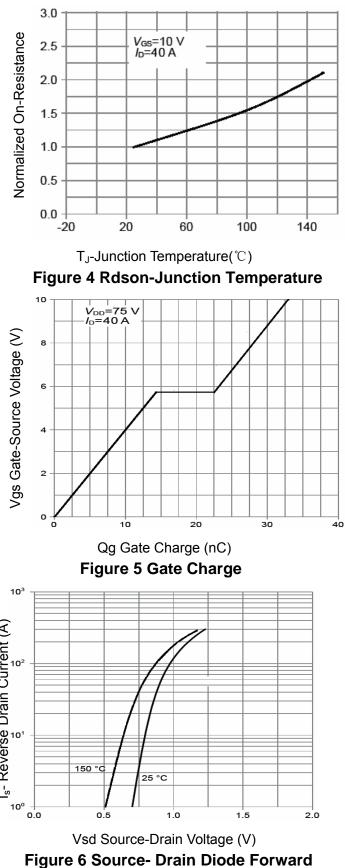
Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t  $\leq$  10 sec. The value of R<sub>8JA</sub> is measured with the device mounted on 1in<sup>2</sup> FR-4 board with 2oz. Copper, in a still air environment with T<sub>A</sub> =25° C. the maximum allowed junction temperature of 150°C. The value in any given application depends on the user's specific board design.
- 3. Pulse Test: Pulse Width  $\leq$  300µs, Duty Cycle  $\leq$  2%.
- 4. Guaranteed by design, not subject to production
- 5.  $E_{AS}$  condition : Tj=25 °C,  $V_{DD}$ =50V,  $V_{G}$ =10V,L=0.5mH, Rg=25 $\Omega$



## **Typical Electrical and Thermal Characteristics**

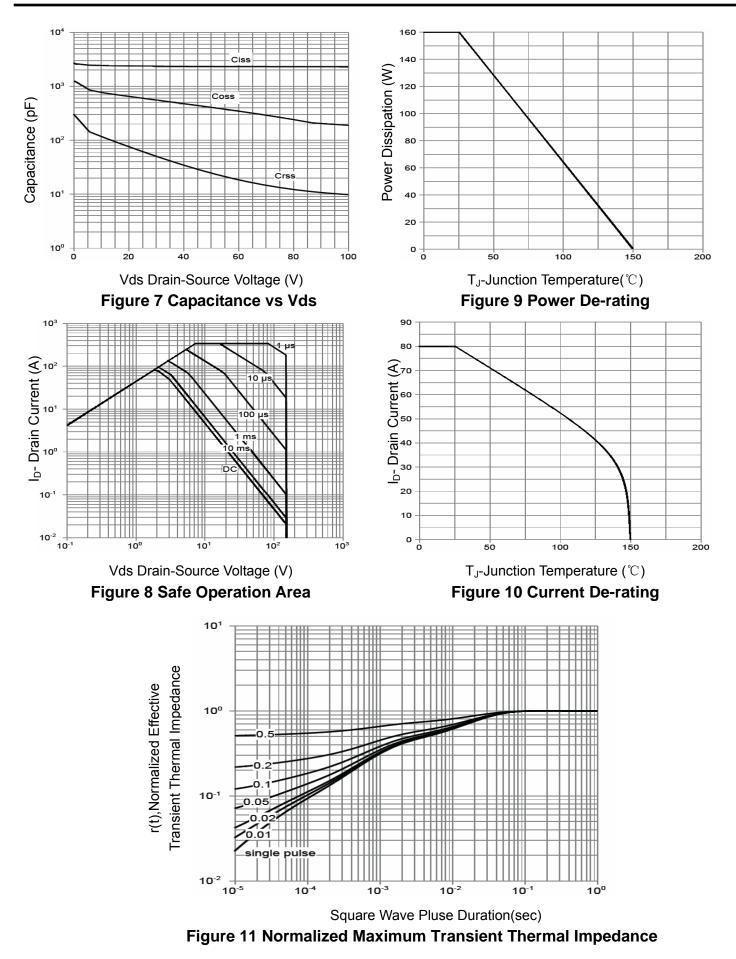






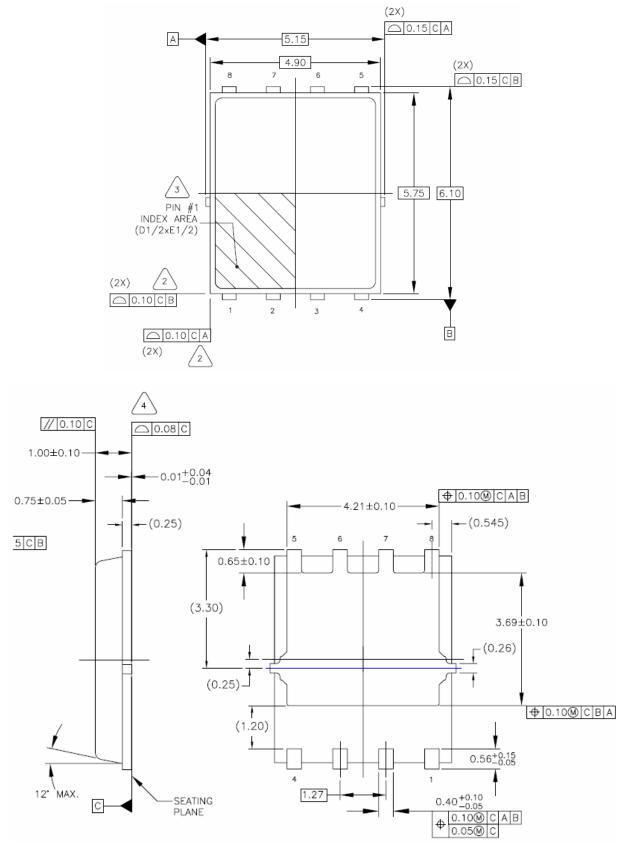
#### http://www.ncepower.com

# NCEP1580GU





## DFN5X6-8L Package Information





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